

Important notice

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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

BCP51; BCX51; BC51PA

45 V, 1 A PNP medium power transistors Rev. 9 — 13 October 2011

Product data sheet

1. **Product profile**

1.1 General description

PNP medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

Product overview Table 1.

Type number[1]	Package	Package		
	NXP	JEITA	JEDEC	
BCP51	SOT223	SC-73	-	BCP54
BCX51	SOT89	SC-62	TO-243	BCX54
BC51PA	SOT1061	-	-	BC54PA

^[1] Valid for all available selection groups.

1.2 Features and benefits

- High current
- Three current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 qualified

1.3 Applications

- Linear voltage regulators
- High-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-45	V
I _C	collector current		-	-	-1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	-2	Α



Table 2. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h _{FE}	DC current gain	$V_{CE} = -2 \text{ V};$ $I_{C} = -150 \text{ mA}$	63	-	250	
	h _{FE} selection -10	$V_{CE} = -2 \text{ V};$ $I_{C} = -150 \text{ mA}$	63	-	160	
	h _{FE} selection -16	$V_{CE} = -2 \text{ V};$ $I_{C} = -150 \text{ mA}$	100	-	250	

2. Pinning information

Table 3. Pinning

Table 3.	Pinning	
Pin	Description	Simplified outline Graphic symbol
SOT223		
1	base	
2	collector	4 2, 4
3	emitter	1—
4	collector	
		sym028
SOT89		
1	emitter	
2	collector	2
3	base	3 2 1 1
		006aaa231
SOT1061		
1	base	
2	emitter	3
3	collector	1 2 sym013 Transparent top view

3. Ordering information

Table 4. Ordering information

Type number[1]	Package					
	Name	Description	Version			
BCP51	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			
BCX51	SC-62	plastic surface-mounted package; collector pad for good heat transfer; 3 leads	SOT89			
BC51PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 2 \times 2 \times 0.65 mm	SOT1061			

^[1] Valid for all available selection groups.

4. Marking

Table 5. Marking codes

Type number	Marking code
BCP51	BCP51
BCP51-10	BCP51/10
BCP51-16	BCP51/16
BCX51	AA
BCX51-10	AC
BCX51-16	AD
BC51PA	BP
BC51-10PA	BQ
BC51-16PA	BR

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		·			
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-45	V
V_{CEO}	collector-emitter voltage	open base	-	-45	V
V_{EBO}	emitter-base voltage	open collector	-	-5	V
Ic	collector current		-	-1	А
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-2	Α
I _B	base current		-	-0.3	А
I _{BM}	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	-0.3	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	BCP51		<u>[1]</u> -	0.65	W
			[2] _	1.00	W
			[3]	1.35	W
	BCX51		<u>[1]</u> -	0.50	W
			[2] _	0.95	W
			[3]	1.35	W
	BC51PA		<u>[1]</u> _	0.42	W
			[2] _	0.83	W
			[3]	1.10	W
			[4]	0.81	W
			[5] _	1.65	W
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

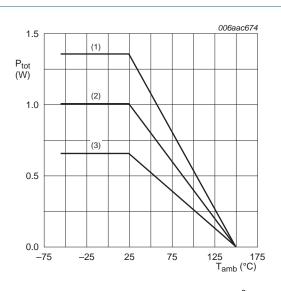
^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

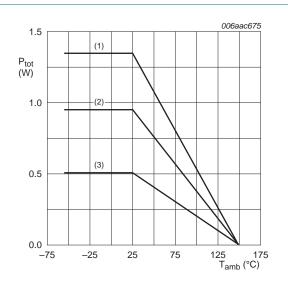
^[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

^[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



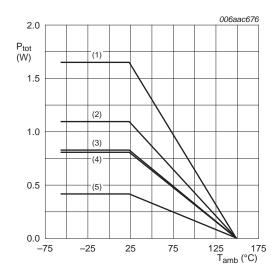
- (1) FR4 PCB, mounting pad for collector 6 cm²
- (2) FR4 PCB, mounting pad for collector 1 cm²
- (3) FR4 PCB, standard footprint

Fig 1. Power derating curves SOT223



- (1) FR4 PCB, mounting pad for collector 6 cm²
- (2) FR4 PCB, mounting pad for collector 1 cm²
- (3) FR4 PCB, standard footprint

Fig 2. Power derating curves SOT89



- (1) FR4 PCB, 4-layer copper, mounting pad for collector 1 cm²
- (2) FR4 PCB, single-sided copper, mounting pad for collector 6 cm²
- (3) FR4 PCB, single-sided copper, mounting pad for collector 1 cm²
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

Fig 3. Power derating curves SOT1061

6. Thermal characteristics

Table 7. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	BCP51		<u>[1]</u> _	-	192	K/W
			[2]	-	125	K/W
			<u>[3]</u> _	-	93	K/W
	BCX51		<u>[1]</u> _	-	250	K/W
			[2] _	-	132	K/W
			[3]	-	93	K/W
	BC51PA		<u>[1]</u> _	-	298	K/W
			[2] _	-	151	K/W
			[3]	-	114	K/W
			<u>[4]</u> _	-	154	K/W
			<u>[5]</u> _	-	76	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point					
	BCP51		-	-	16	K/W
	BCX51		-	-	16	K/W
	BC51PA		-	-	20	K/W

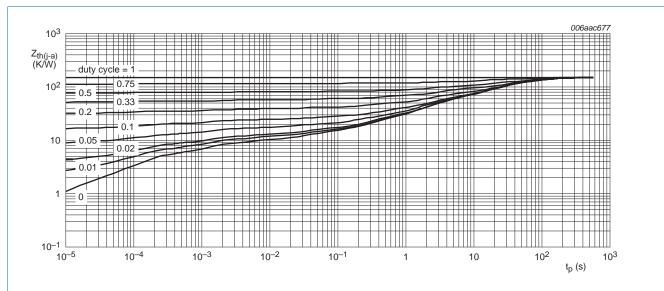
^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

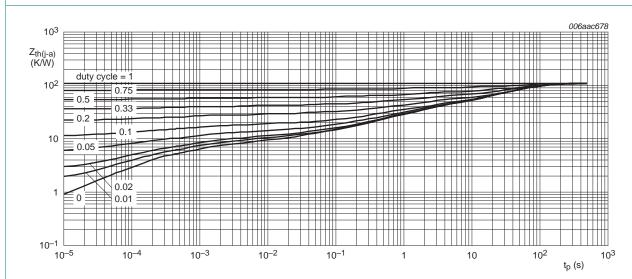
^[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

^[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



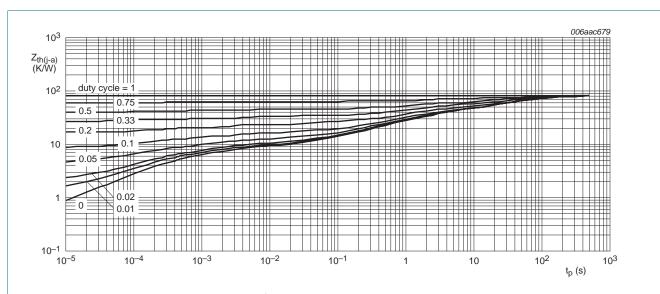
FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



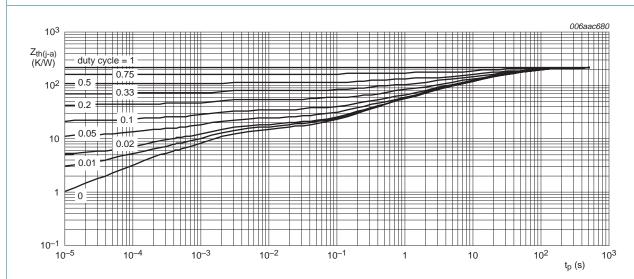
FR4 PCB, mounting pad for collector 1 cm²

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



FR4 PCB, mounting pad for collector 6 cm²

Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



FR4 PCB, standard footprint

Fig 7. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values

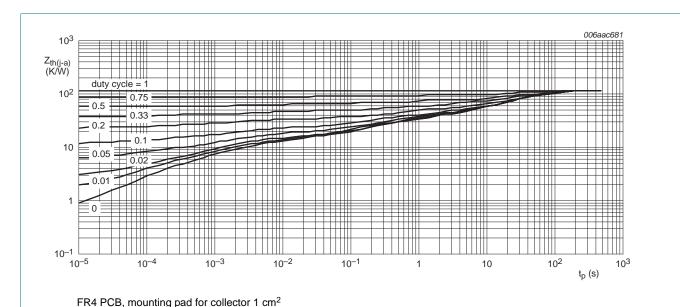


Fig 8. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89;

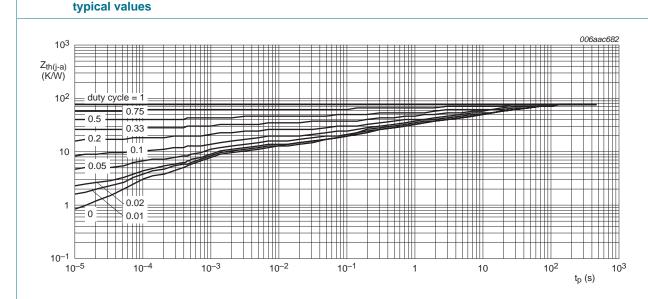
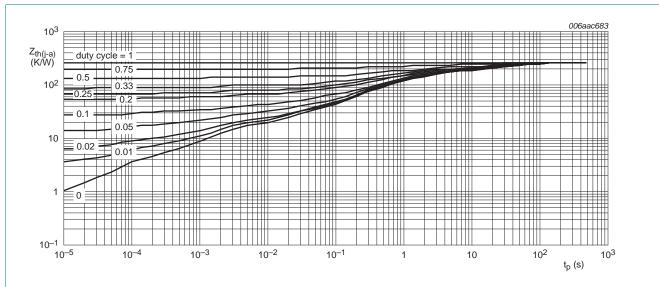


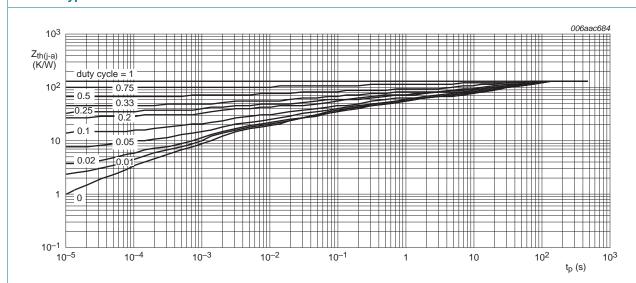
Fig 9. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values

FR4 PCB, mounting pad for collector 6 cm²



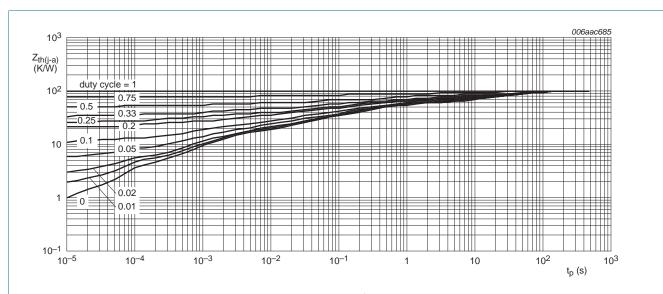
FR4 PCB, single-sided copper, standard footprint

Fig 10. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values



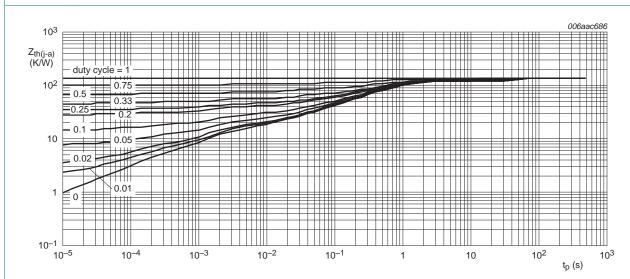
FR4 PCB, single-sided copper, mounting pad for collector 1 cm²

Fig 11. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values



FR4 PCB, single-sided copper, mounting pad for collector $6\ cm^2$

Fig 12. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values



FR4 PCB, 4-layer copper, standard footprint

Fig 13. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values

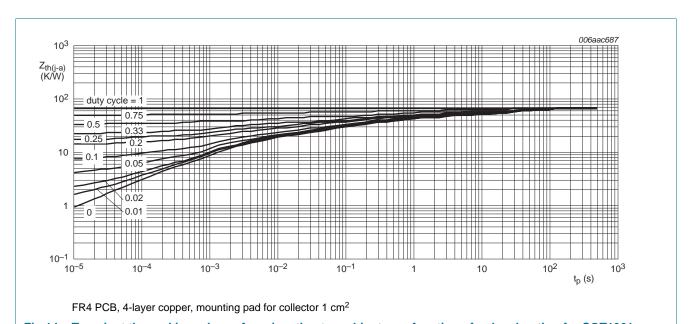


Fig 14. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values

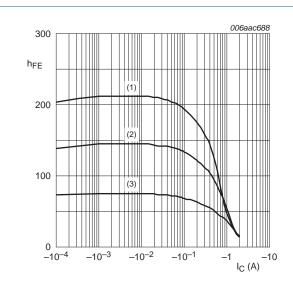
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I_{CBO}	collector-base	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$		-	-	-100	nA
	cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$		-	-	-10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$		-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -2 V$					
		$I_C = -5 \text{ mA}$		63	-	-	
		$I_C = -150 \text{ mA}$		63	-	250	
		$I_C = -500 \text{ mA}$	[1]	40	-	-	
	DC current gain	$V_{CE} = -2 V$					
	h _{FE} selection -10	$I_C = -150 \text{ mA}$		63	-	160	
	h _{FE} selection -16	$I_C = -150 \text{ mA}$		100	-	250	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -500 \text{ mA};$ $I_B = -50 \text{ mA}$	[1]	-	-	-0.5	V
V_{BE}	base-emitter voltage	$V_{CE} = -2 \text{ V}; I_{C} = -500 \text{ mA}$	[1]	-	-	-1	V
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	15	-	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -50 \text{ mA};$ f = 100 MHz		-	145	-	MHz

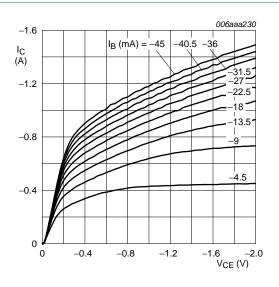
^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta = 0.02.$



$$V_{CE} = -2 V$$

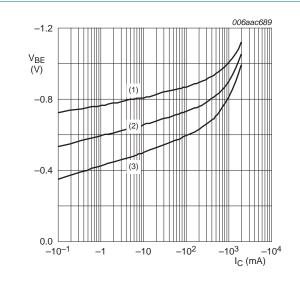
- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 15. DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

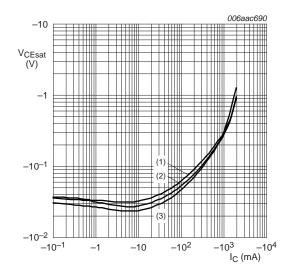
Fig 16. Collector current as a function of collector-emitter voltage; typical values





- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) T_{amb} = 100 °C

Fig 17. Base-emitter voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

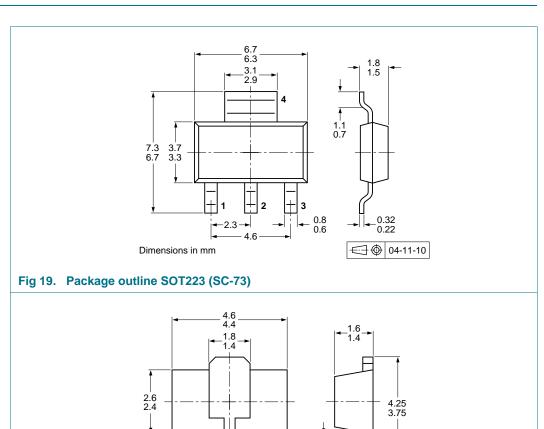
Fig 18. Collector-emitter saturation voltage as a function of collector current; typical values

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



1.2 0.8

⊕ 06-08-29

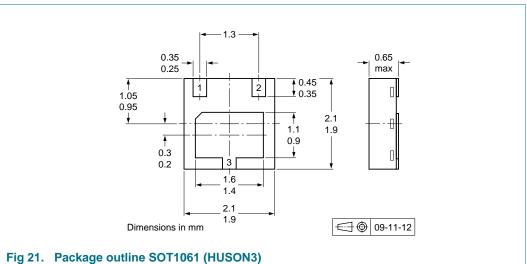
0.48 0.35

Fig 20. Package outline SOT89 (SC-62/TO-243)

Dimensions in mm

0.53

-1.5



10. Packing information

Packing methods Table 9.

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Туре	Package	•		Packing quantity		
number[2]				1000	3000	4000
BCP51	SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135
BCX51 SOT89		8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135
		8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-
BC51PA	SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-

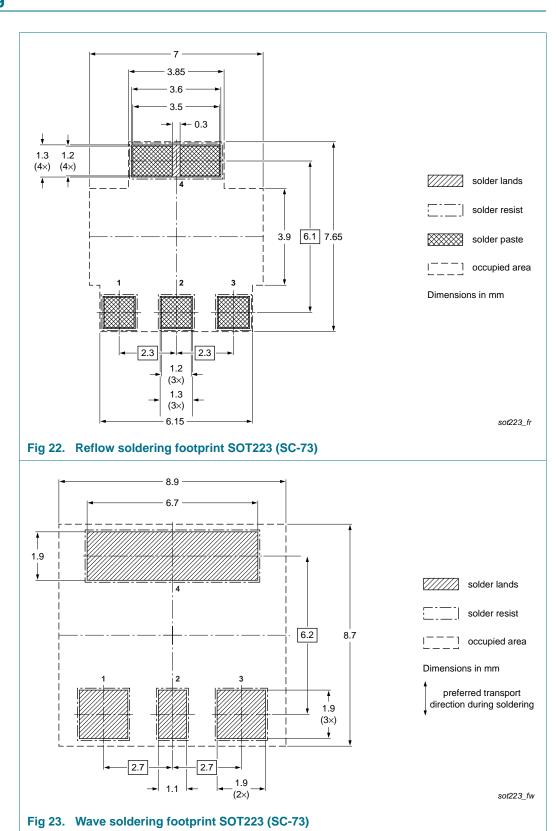
^[1] For further information and the availability of packing methods, see Section 14.

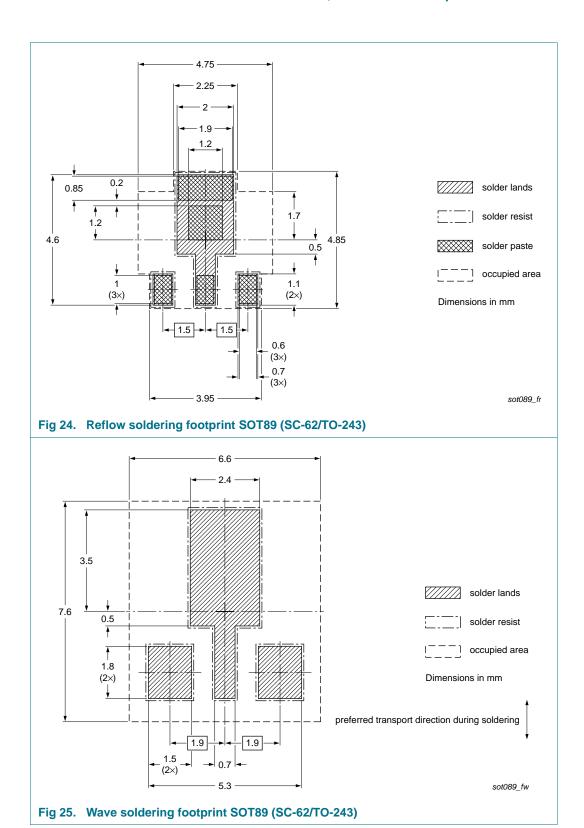
Valid for all available selection groups.

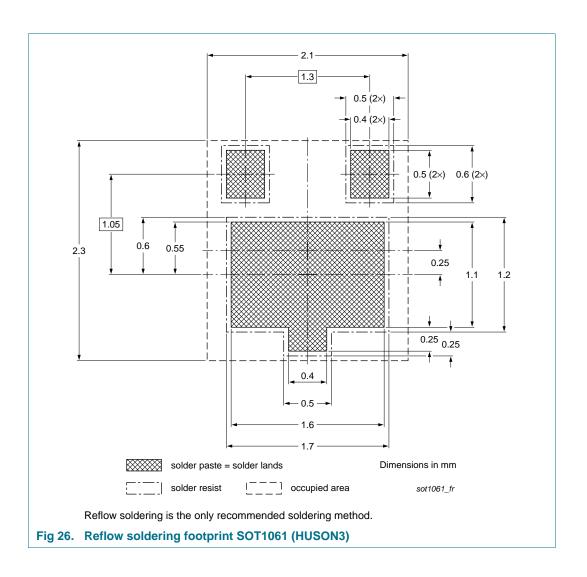
T1: normal taping

^[4] T3: 90° rotated taping

11. Soldering







12. Revision history

Table 10. Revision history

,							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
BCP51_BCX51_BC51PA v.9	20111013	Product data sheet	-	BC636_BCP51_BCX51 v.8			
Modifications:	 Deleted typ 	Deleted type number BC636					
	 Added Type 	e number BC51PA					
	Section 1 "F	Product profile": updated					
	 Table 6 and 	I 7: updated according to la	atest measuremen	ts			
	• Figure 1 to	9, <u>15, 17, 18</u> and <u>21</u> : upda	ited				
	 Figure 10 to 	1 <u>4</u> : added					
	Section 8 "	Test information": added					
	 Section 11 ⁶ 	"Soldering": added					
	• Section 13	"Legal information": update	ed				
BC636_BCP51_BCX51 v.8	20080222	Product data sheet	-	BC636_BCP51_BCX51 v.7			
BC636_BCP51_BCX51 v.7	20070629	Product data sheet	-	BC636_BCP51_BCX51 v.6			
BC636_BCP51_BCX51 v.6	20060329	Product data sheet	-	BC636_638_640 v.5			
				BCP51_52_53 v.5			
				BCX51_52_53 v.4			
BC636_638_640 v.5	20041011	Product specification	-	BC636_638_640 v.4			
BCP51_52_53 v.5	20030206	Product specification	-	BCP51_52_53 v.4			
BCX51_52_53 v.4	20011010	Product specification	-	BCX51_52_53 v.3			

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

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BCP51_BCX51_BC51PA

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BCP51; BCX51; BC51PA

45 V, 1 A PNP medium power transistors

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

15. Contents

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